



# Capacitors



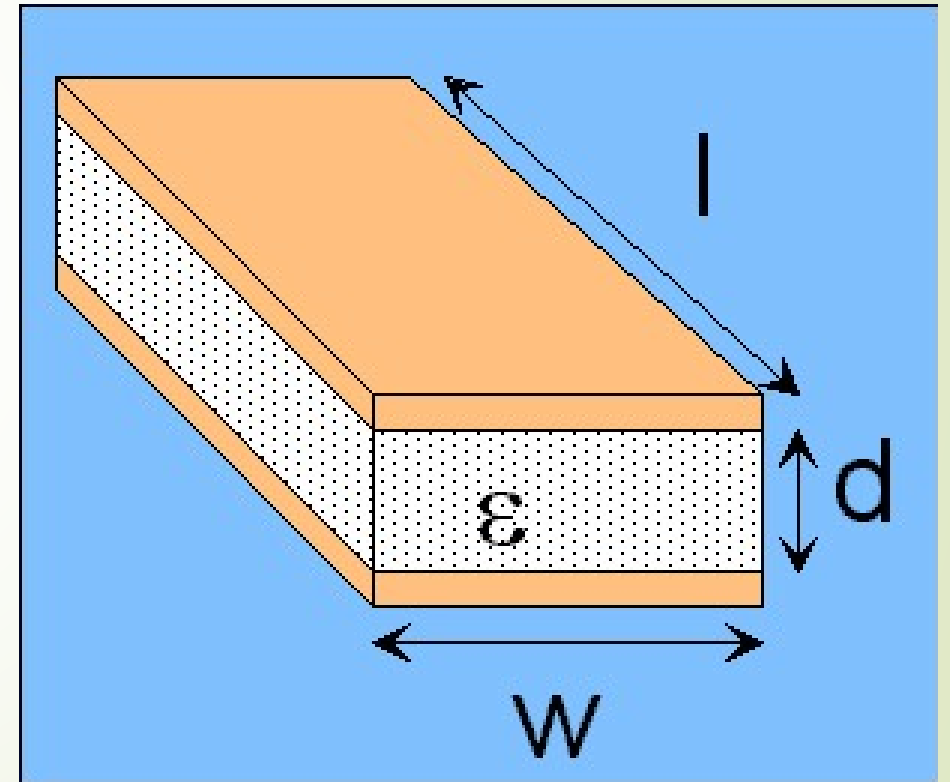
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4/17/2015

# Parallel-plate capacitor

$$C = l \cdot \epsilon \cdot \frac{w}{d}$$


The equation assumes that there are no significant fringing fields or

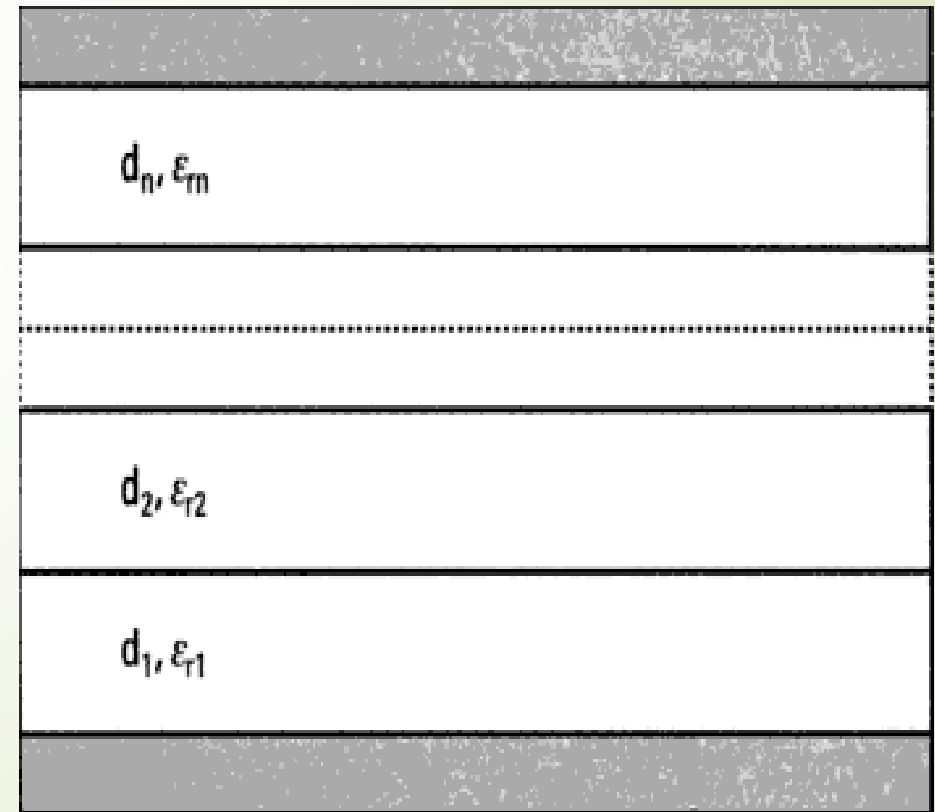
$$\begin{aligned}d &\ll l \\d &\ll w \\ \epsilon_r &\gg \epsilon_0\end{aligned}$$



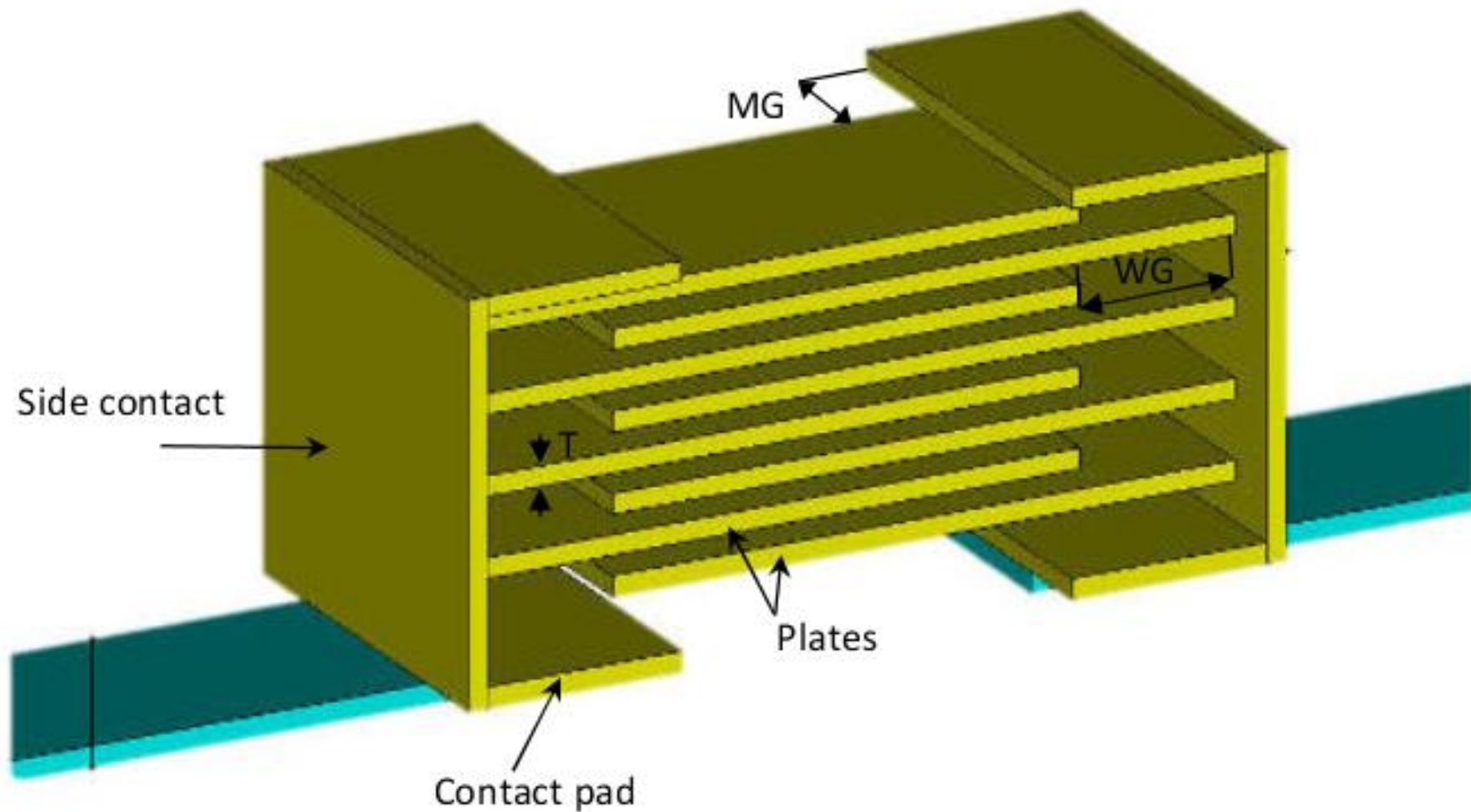
# Multilayer dielectric parallel plate capacitor

$$\epsilon_{r,layered} = \left( \sum_{n=1}^{all\ layers} \frac{d_n}{d_t \cdot \epsilon_{r,n}} \right)^{-1}$$


$$C = \epsilon_{r,layered} \cdot \frac{A}{d_t}$$



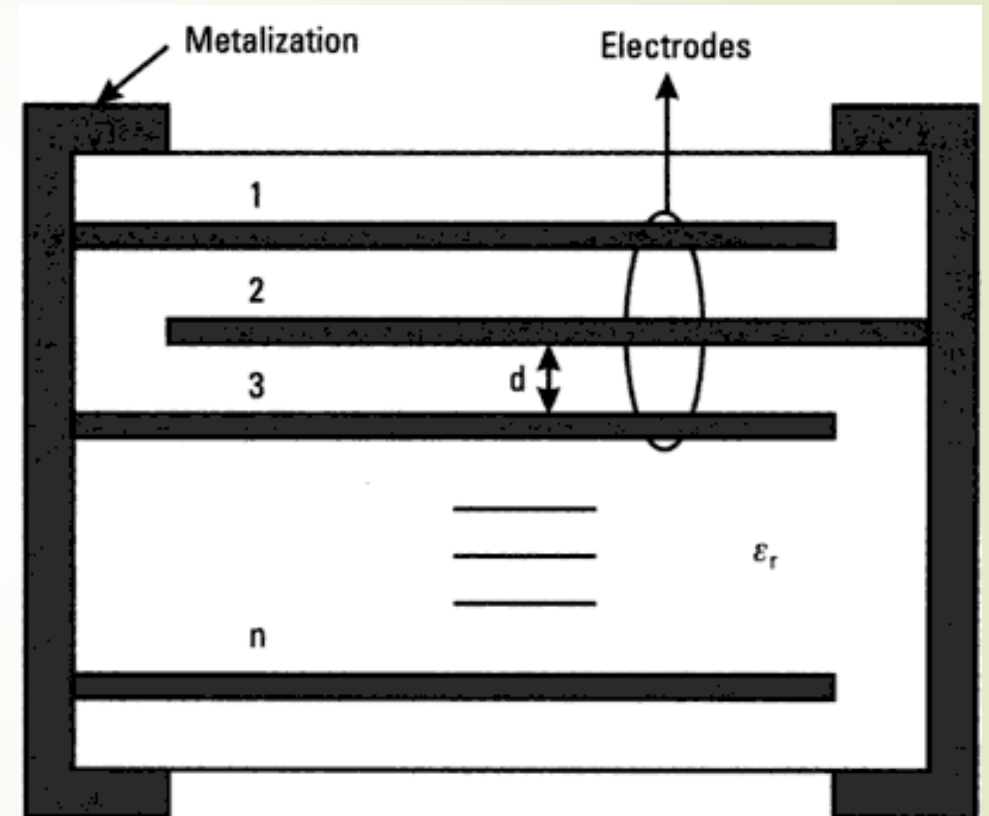
# Multilayer capacitor



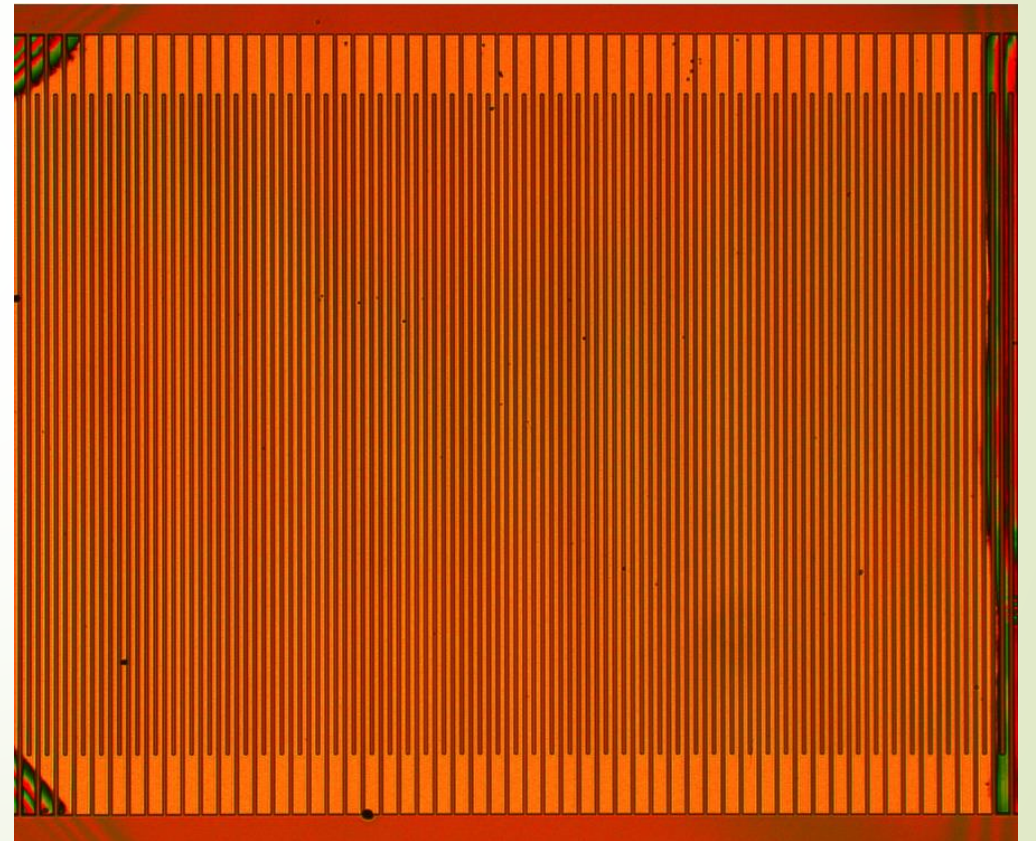
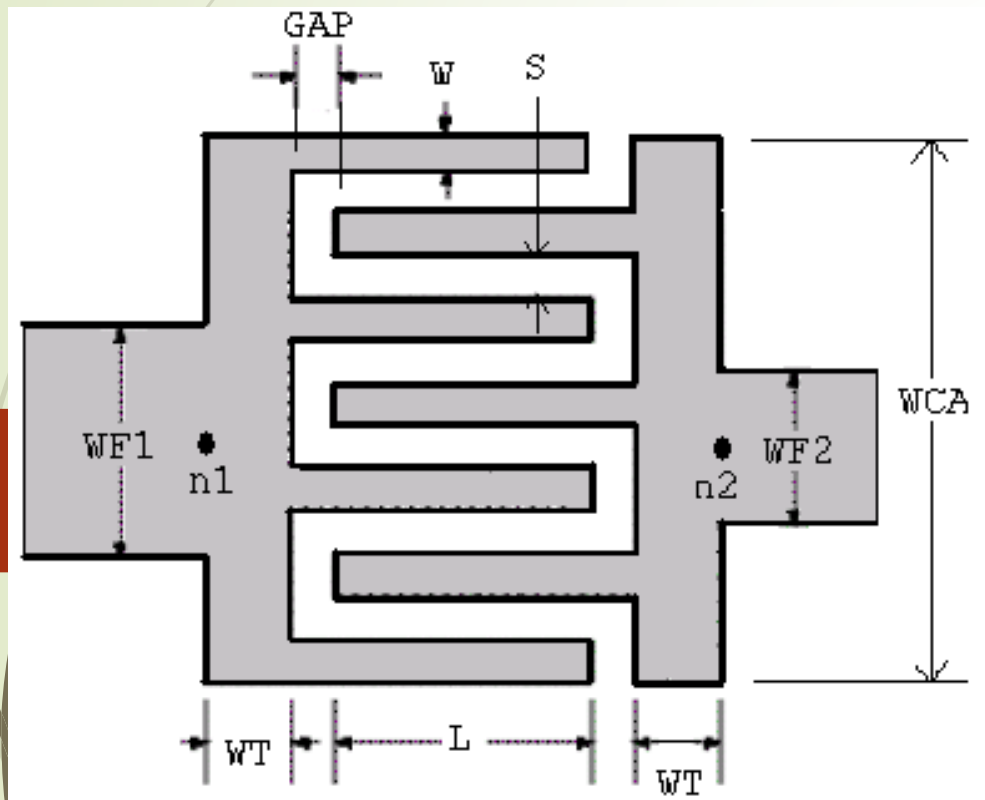
$$C = \frac{0.2249 \epsilon_r A (n-1)}{d} \text{ (pF)}$$

Where

A=area of plates in square inches  
n=number of conductor layers  
d=plate spacing



# Interdigital capacitor



# Model 1

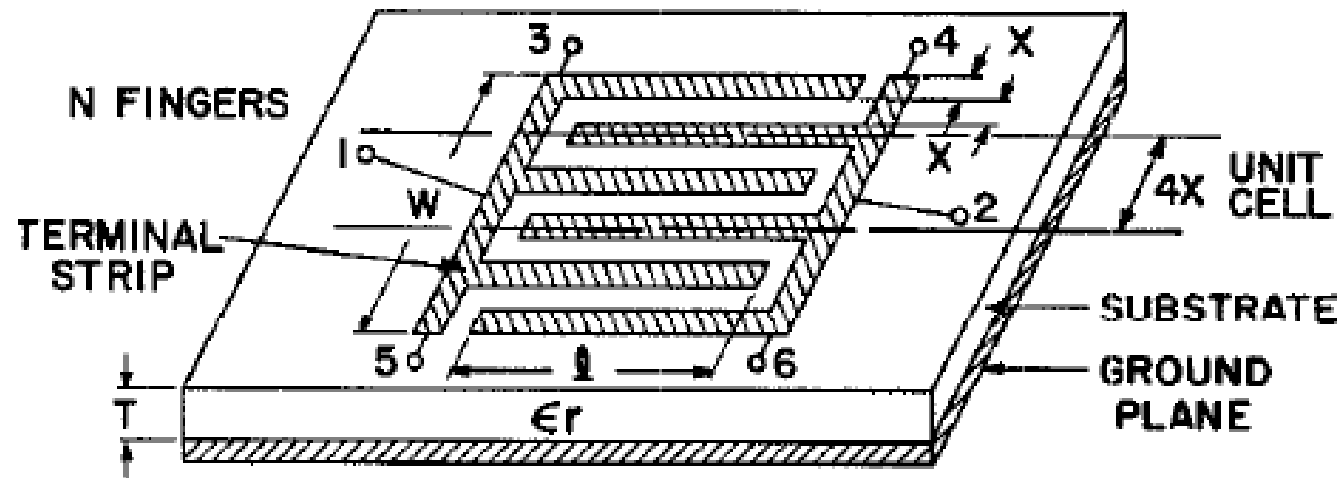
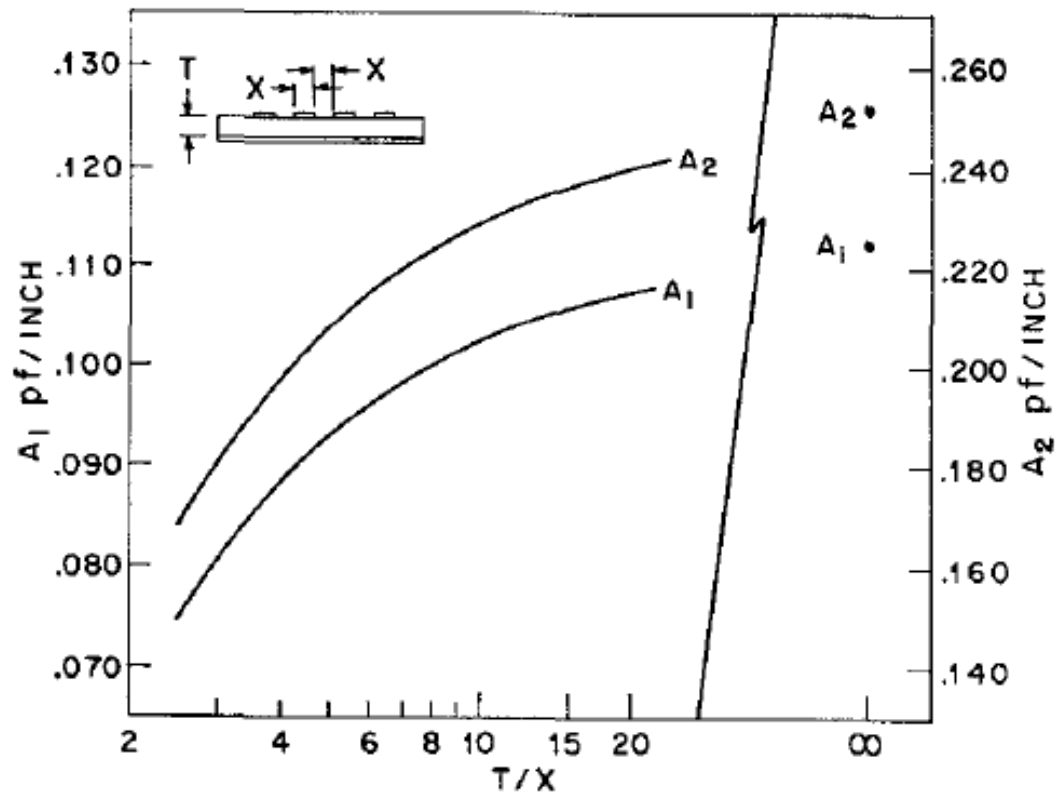


Fig. 1. Interdigital capacitor.

$$C = \frac{\epsilon_r + 1}{d} \cdot l \cdot [(N - 3)A_1 + A_2] \text{ (pF/in)}$$

Valid only When

$$g = x,$$
$$h > \frac{w}{N},$$



Generally,  $A_1, A_2$  can be considered as two constants.

The equations is valid to better than 0.35% for

$$3 \leq \frac{t}{x}$$



For our pattern

$$g = x = 10\mu\text{m}$$

$$h > \frac{w}{N} = \frac{5\text{mm}}{250} = 0.02\text{mm}$$

$$3 \leq \frac{t}{x} = \frac{100\text{nm}}{10\mu\text{m}} = 0.01$$

and

$$l = 2.4\text{mm},$$

$$N = 250,$$

$$\epsilon_r = 10,$$

$$A_1 = 0.1111\text{pF/inch}$$

$$A_2 = 0.249\text{pF/inch}$$

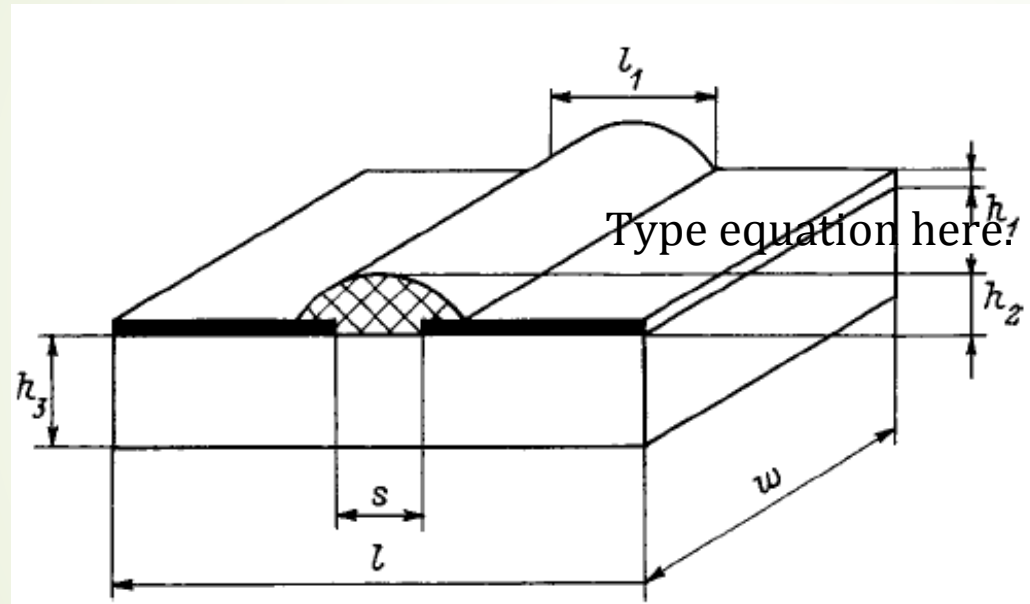
We get

$$C = 146.2069 \text{ pF/inch}$$

Or,

$$C = 146.2069 \text{ pF/inch} * 0.1969 \text{ in} = 28.7809 \text{ pF}$$

# Model 2



$$C = (N - 1)\epsilon_0 w \cdot \left\{ \frac{2}{\pi} \left[ \ln \left( \frac{w}{s} \right) + 1 \right] + \frac{\epsilon_3 - 1}{\pi} \ln \left( 16 \frac{h_3 + h_2}{\pi s} \right) + \frac{\epsilon_2 - 1}{\frac{s}{h_2} + \frac{4}{\pi} \ln 2 \sqrt{1 + \frac{2\epsilon_2}{\alpha h_2}}} \right\}$$

For our pattern

$$g = s = 10\mu m, w = 2.4mm$$

$$h_2 = 100nm, h_3 = 0.5mm$$

$$l = 30\mu m$$

$$N = 250,$$

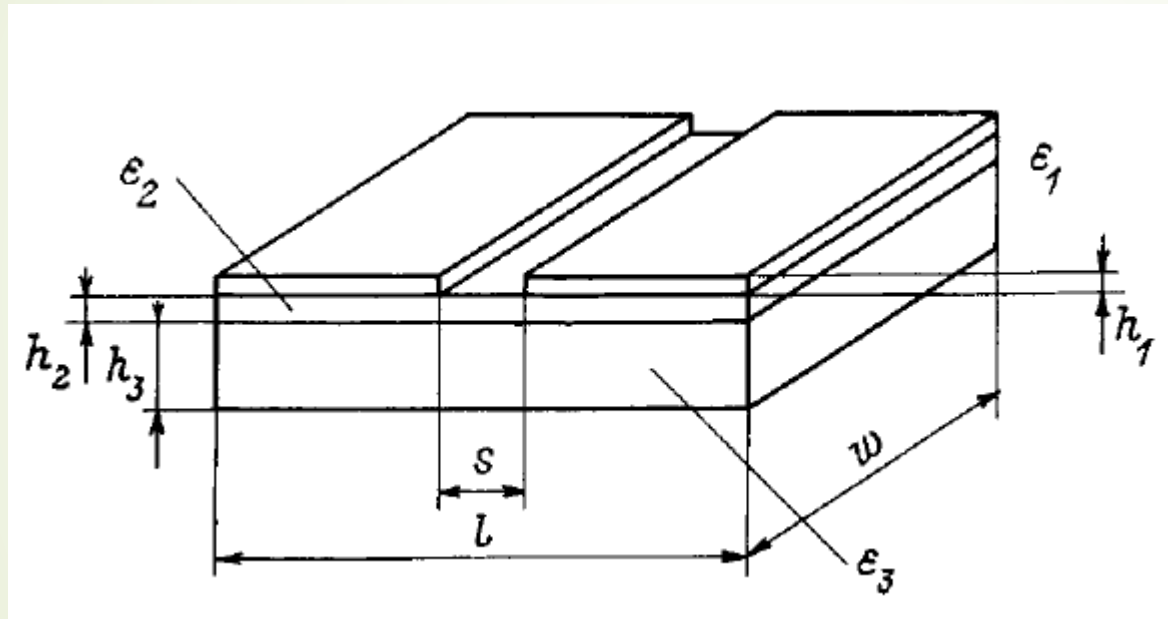
$$\epsilon_3 = 10$$

$$\epsilon_2 = 100$$

We get

$$C = 53.1Pf$$

# Model 3



$$C = (N - 1)\epsilon_0 w \cdot \left\{ \frac{2}{\pi} \ln(4l/s) + \frac{\epsilon_3 - 1}{\pi} \ln \left( 16 \frac{h_3 + h_2}{\pi s} \right) + \frac{\epsilon_2 - 3}{\frac{s}{h_2} + \frac{4}{\pi} \ln 2 \sqrt{1 + \frac{2\epsilon_2}{\alpha h_2}}} \right\}$$

For our pattern

$$g = s = 10\mu m, w = 2.4mm$$

$$h_2 = 50nm, h_3 = 0.5mm$$

$$l = 30\mu m$$

$$N = 250,$$

$$\epsilon_3 = 10$$

$$\epsilon_2 = 100$$

We get

$$C = 44.9Pf$$



Thanks!